



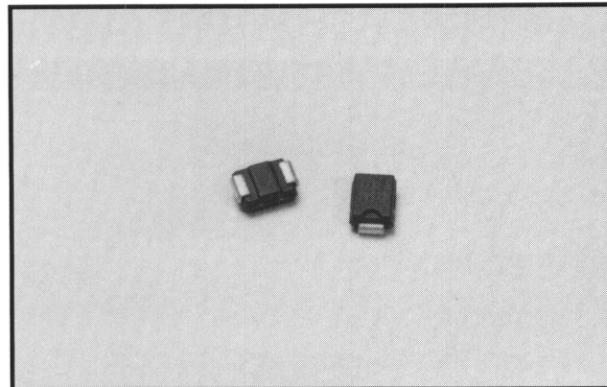
## **1.5 AMP SURFACE MOUNT GLASS PASSIVATED SILICON RECTIFIER**

### **■ FEATURES**

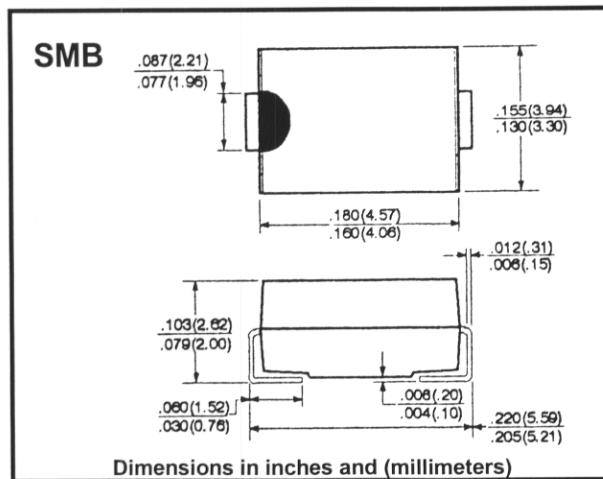
- Rating to 1000V PRV
- For surface mount applications
- Easy pick and place
- Glass passivated junction
- UL recognized 94V-O plastic material
- High temperature soldering: 250 °C/10 seconds at terminal
- Terminal solderable per MIL-STD-202 Method 208
- Surge overload rating to 50A peak

### **■ Mechanical Data**

- Case: Molded Plastic
- Polarity: Indicated on cathode
- Terminal: Solder plated copper
- Packaging: 12mm tape (EIA STD RS-481)
- Weight: 0.003 ounces, 0.093 grams



### **■ Outline Drawing**



### **■ Maximum Ratings & Characteristics**

- Ratings at 25° C ambient temperature unless otherwise specified
- Single phase, half wave, 60Hz, resistive or inductive load
- For capacitive load, derate current by 20%

		S2A	S2B	S2D	S2G	S2J	S2K	S2M	Units
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	V
Maximum RMS Input Voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	V
Maximum Average Forward Output Current @ T <sub>L</sub> = 100°C	I <sub>(AV)</sub>				1.5				A
Peak Forward Surge Current 8.3 ms Single Half-Sine-Wave Superimposed On Rated Load	I <sub>FSM</sub>				50				A
Maximum DC Forward Voltage Drop Per Element At 1.5A DC	V <sub>F</sub>				1.15				V
Maximum Reverse Current At Rated DC Blocking Voltage per Element @ T <sub>A</sub> = 25°C	I <sub>R</sub>				5.0				µA
					125				µA
Typical Junction Capacitance *(See Note)	C <sub>J</sub>				20				pF
Maximum Thermal Resistance***(See Note)	R <sub>(THJL)</sub>				20				°C/W
Operating Temperature Range	T <sub>J</sub>				-65 to +150				°C
Storage Temperature Range	T <sub>STG</sub>				-65 to +150				°C

Note: \*Measured at 1.0 MHz and applied reverse voltage of 4.0V DC

\*\*Thermal resistance junction to lead